



Powerline N-Channel IGBT

Advance Information

Supersedes February 1998 version, DS4711 - 2.4

DS4711 - 3.0 March 1998

The ITS08F06 is a robust n-channel, enhancement mode insulated gate bipolar transistor (IGBT) designed for low power dissipation in a wide range of high voltage applications such as power supplies and motor drives. The high impedance gate simplifies gate drive considerations, allowing operation directly from low power control circuitry.

Fast rise and fall times allow very high frequency switching making the device suitable for modern systems employing high frequency switching.

Low saturation voltages minimise power dissipation, thereby reducing the cost of the overall system in which they are used.

The ITS is fully short circuit rated making it especially suited for motor control and other applications requiring short circuit withstand capacity. Each device in the Powerline range is available with or without an integral anti-parallel ultrafast soft recovery diode, see separate datasheet for co-pack device.

Typical applications include high frequency inverters for motor control, welding and heating apparatus. The Powerline range of IGBTs is also applicable to switched mode and uninterruptible power supplies.

FEATURES

- Enhancement Mode n-Channel Device
- High Switching Speed
- Low On-state Saturation Voltage
- High Input Impedance Simplifies Gate Drive
- TO220 and TO252 Package Options
- Short Circuit Rated

APPLICATIONS

- High Frequency Inverters
- Motor Control
- Switched Mode Power Supplies
- High Frequency Welding
- Heating/Cooking Apparatus

ORDERING INFORMATION

ITS08F06B TO220

ITS08F06G TO252 SMD (tape and reel)

ITS08F06H TO252 SMD (tubes)

KEY PARAMETERS

V _{CES}	(max)	600V
V _{CE(sat)}	(typ)	2.1V
I _{C25}	(max)	14A
I _{C85}	(max)	8 A
I _{CM}	(max)	16A
t _{sc}	(max)	10 μ s

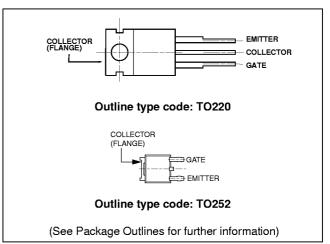


Fig.1 Pin connections - top view (not to scale)

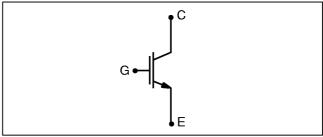


Fig.2 ITS08F06 circuit

ITS08F06

ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions		Units
V _{CES}	Collector-emitter voltage	$V_{GE} = 0V$	600	٧
V _{GES}	Gate-emitter voltage	-	±20	٧
I _{C25}	Continuous collector current	T _{case} = 25°C	14	Α
I _{C85} Continuous collector current		$T_{case} = 85^{\circ}C$	8	Α
I _{CM}	Pulsed collector current	1ms, T _{case} = 85°C	16	Α
P _{tot}	Power dissipation	$T_{case} = 85^{\circ}C$	30	w

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance	DC junction to case	-	2.1	°C/W
T _{OP}	Operating junction temperature range	-	-40	150	°C
T _{stg}	Storage temperature range	-	-40	150	°C
-	Mounting torque	M3 screw	-	1.1	Nm

DC ELECTRICAL CHARACTERISTICS

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I _{CES}	Collector cut-off current	V _{GE} = 0V, V _{CE} = 600V	-	-	0.5	mA
I _{GES}	Gate leakage current	V _{GE} = 20V, V _{CE} = 0V	-	-	±500	nA
V _{GE(TH)}	Gate threshold voltage	$I_{\rm C}$ = 0.25mA, $V_{\rm CE}$ = $V_{\rm GE}$	4	6	7.5	٧
V _{CE(SAT)}	Collector-emitter saturation voltage	V _{GE} = 15V, I _C = 8A	-	2.1	2.7	٧
		$V_{GE} = 15V, I_{C} = 8A, T_{j} = 125^{\circ}C$	-	2.4	-	٧

AC ELECTRICAL CHARACTERISTICS

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
C _{ies}	Input capacitance	V _{CE} = 25V, V _{GE} = 15V, f = 1MHz	-	500	-	рF
C _{oes}	Output capacitance	V _{CE} = 25V, V _{GE} = 15V, f = 1MHz	-	130	-	pF
C _{res}	Reverse transfer capacitance	V _{CE} = 25V, V _{GE} = 15V, f = 1MHz	-	120	-	рF

INDUCTIVE SWITCHING CHARACTERISTICS - see figures 3 to 5

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{d(ON)}	Turn-on delay time		-	100	-	ns
t,	Rise time	Ι ολ	-	16	-	ns
E _{on}	Turn-on energy loss - per cycle	$I_{c} = 8A,$ $V_{GE} = \pm 15V,$	-	0.08	-	mJ
t _{d(OFF)}	Turn-off delay time	$V_{CE} = 50\%V_{ces}$	-	120	-	ns
t,	Fall time	$R_{G(ON)} = R_{G(OFF)} = 25\Omega$	-	300	500	ns
E _{OFF}	Turn-off energy loss - per cycle		-	0.35	-	mJ
T _{case} = 125°	C unless stated otherwise.					
t _{d(ON)}	Turn-on delay time		-	100	-	ns
t,	Rise time	, , , , , , , , , , , , , , , , , , , ,	-	16	-	ns
E _{on}	Turn-on energy loss - per cycle	$I_{c}=8A,$ $V_{GE}=\pm15V,$ $V_{CE}=50\%V_{ces}$ $R_{G(ON)}=R_{G(OFF)}=25\Omega$	-	0.13	-	mJ
t _{d(OFF)}	Turn-off delay time		-	120	-	ns
t,	Fall time		-	500	-	ns
E _{OFF}	Turn-off energy loss - per cycle		-	0.55	-	mJ

SHORT CIRCUIT RATING

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{sc}	Short circuit withstand time	$T_c = 125^{\circ}C, V_{GE} = 15V, V_{CE} = 50\% V_{CES}$	-	ı	10	μs

ITS08F06

BASIC TEST CIRCUIT AND SWITCHING DEFINITIONS

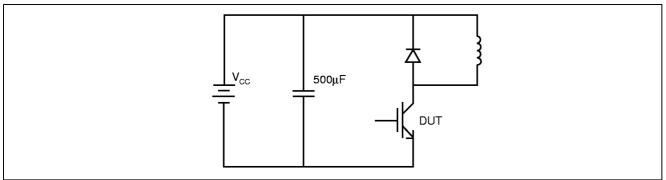


Fig.3 Basic d.c. chopper ciruit

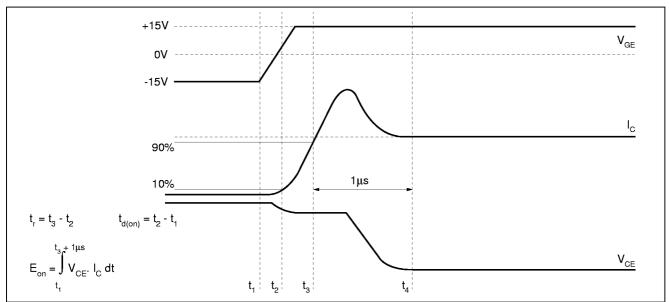


Fig.4 Turn-on characteristics

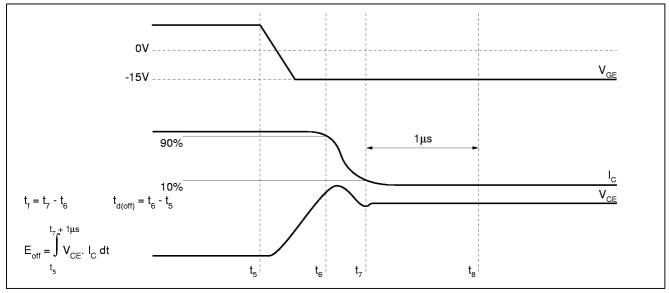


Fig.5 Turn-off characteristics

CURVES

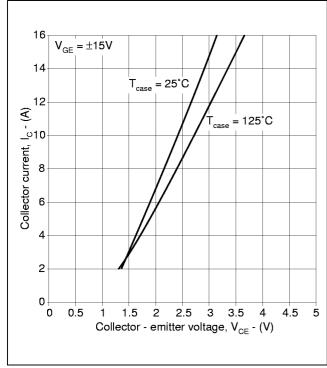


Fig.6 Typical output characteristics

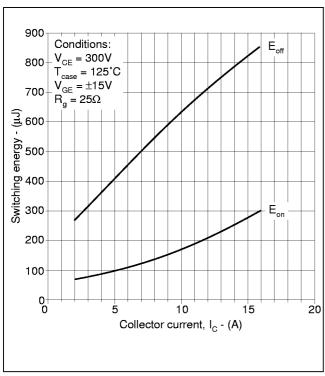


Fig.8 Typical switching losses vs collector current

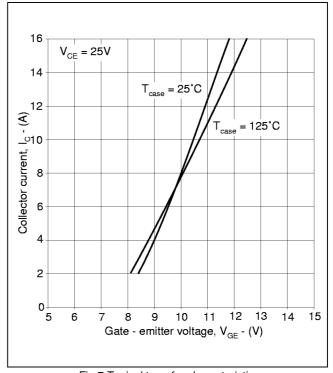


Fig.7 Typical transfer characteristics

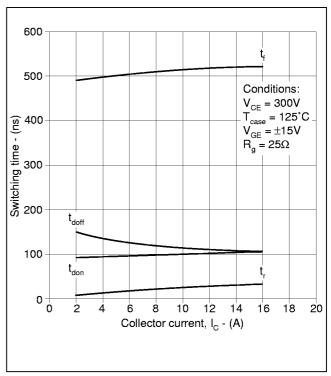


Fig.9 Typical switching times vs collector current

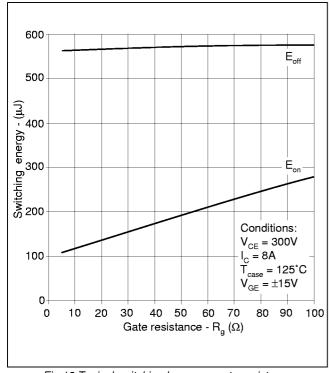


Fig.10 Typical switching losses vs gate resistance

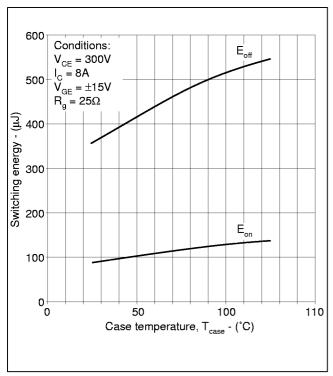


Fig.12 Typical switching losses vs case temperature

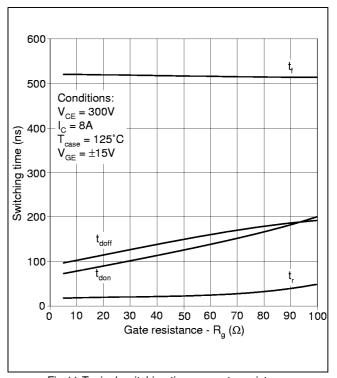


Fig.11 Typical switching times vs gate resistance

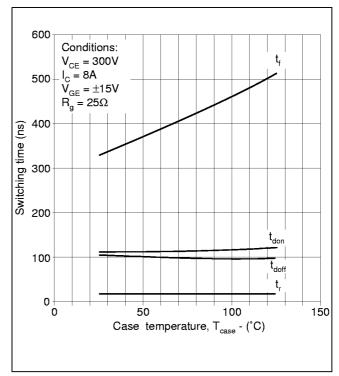
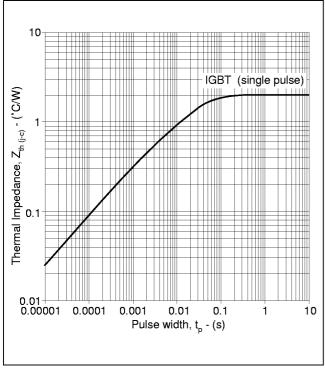


Fig.13 Typical switching time vs case temperature



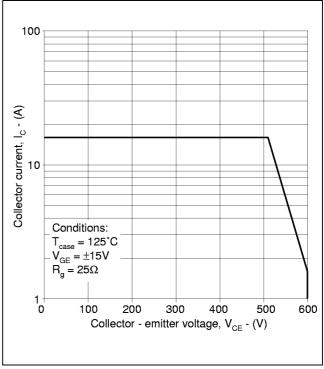
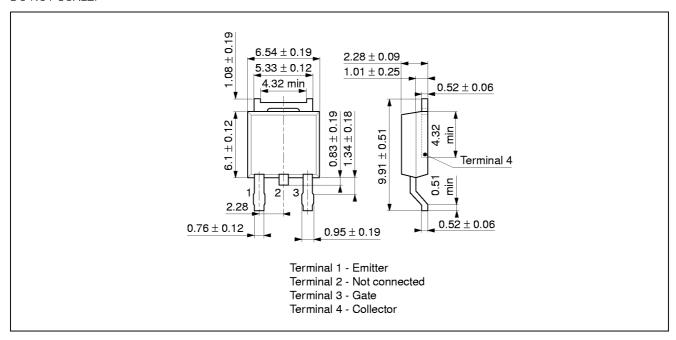


Fig.14 Transient thermal impedance - junction to case

Fig.15 Reverse bias safe operating area

PACKAGE OUTLINE - TO252

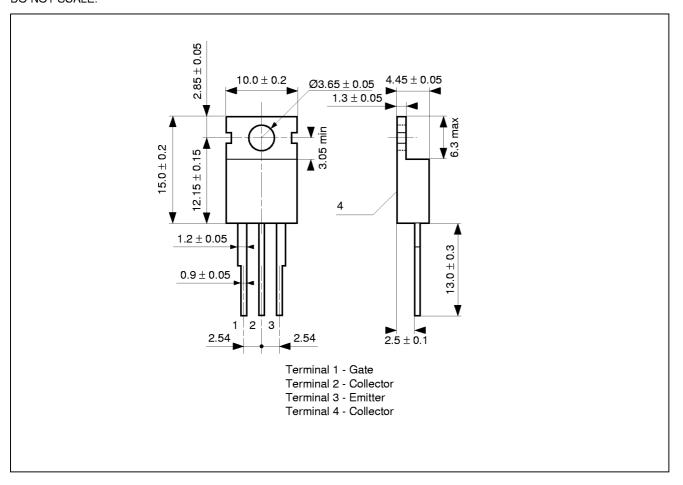
For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



ITS08F06

PACKAGE OUTLINE - TO220

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